



# **Ultrahigh-Speed Switching Applications**

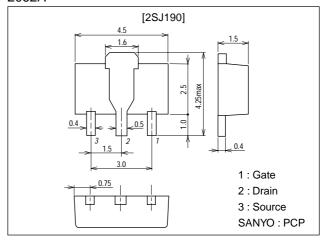
#### **Features**

- · Low ON resistance.
- · Ultrahigh-speed switching.
- · Low-voltage drive.

# **Package Dimensions**

unit:mm

2062A



## **Specifications**

### Absolute Maximum Ratings at Ta = 25°C

| Parameter                   | Symbol           | Conditions   | Ratings     | Unit |
|-----------------------------|------------------|--|-------------|------|
| Drain-to-Source Voltage     | V <sub>DSS</sub> |  | -60         | V    |
| Gate-to-Source Voltage      | VGSS             |  | ±15         | V    |
| Drain Current (DC)          | ΙD               |  | -1          | Α    |
| Drain Current (Pulse)       | I <sub>DP</sub>  | PW≤10μs, duty cycle≤1%                               | -4          | Α    |
| Allowable Power Dissipation | D-               | Tc=25°C  | 3.5         | W    |
|                             | P <sub>D</sub>   | Mounted on ceramic board (250mm <sup>2</sup> ×0.8mm) | 1.5         | W    |
| Channel Temperature         | Tch              |  | 150         | °C   |
| Storage Temperature         | Tstg             |  | -55 to +150 | °C   |

#### Electrical Characteristics at Ta = 25°C

| Parameter                                  | Symbol               | Conditions                                    | Ratings |     |      | Unit  |
|--|----------------------|---|---------|-----|------|-------|
|  |                      |   | min     | typ | max  | Offic |
| Drain-to-Source Breakdown Voltage          | V(BR)DSS             | $I_D=-1$ mA, $V_{GS}=0$                       | -60     |     |      | V     |
| Zero-Gate Voltage Drain Current            | IDSS                 | V <sub>DS</sub> =-60V, V <sub>GS</sub> =0     |         |     | -100 | μΑ    |
| Gate-to-Source Leakage Current             | IGSS                 | V <sub>GS</sub> =±12V, V <sub>DS</sub> =0     |         |     | ±10  | μΑ    |
| Cutoff Voltage                             | V <sub>GS(off)</sub> | V <sub>DS</sub> =-10V, I <sub>D</sub> =-1mA   | -1.0    |     | -2.0 | V     |
| Forward Transfer Admittance                | yfs                  | V <sub>DS</sub> =-10V, I <sub>D</sub> =-500mA | 0.6     | 1.0 |      | S     |
| Static Drain-to-Source ON-State Resistance | R <sub>DS(on)</sub>  | I <sub>D</sub> =-500mA, V <sub>GS</sub> =-10V |         | 0.9 | 1.2  | Ω     |
|  | R <sub>DS(on)</sub>  | I <sub>D</sub> =-500mA, V <sub>GS</sub> =-4V  |         | 1.2 | 1.6  | Ω     |

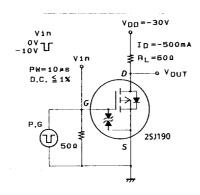
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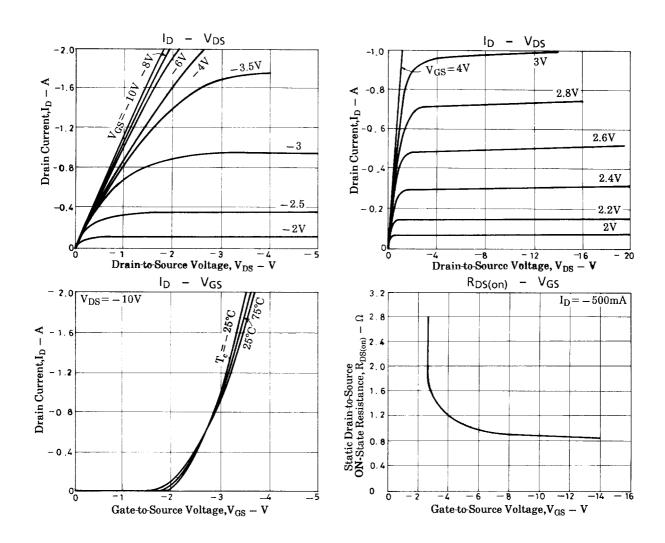
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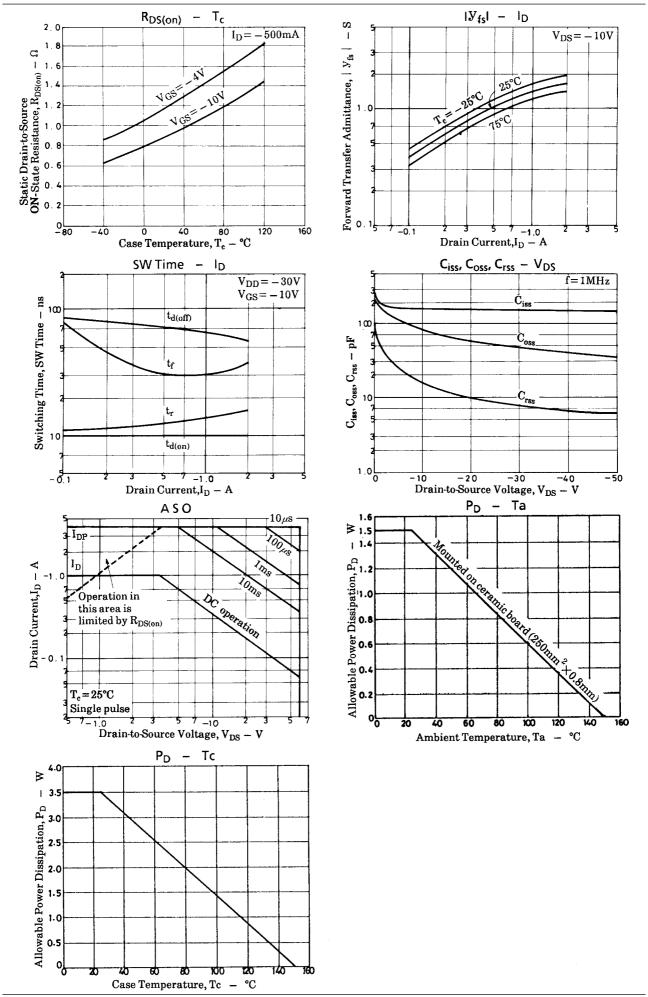
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| Parameter                    | Symbol               | Conditions                              | Ratings |      |     | Unit |
|------------------------------|----------------------|---|---------|------|-----|------|
|                              |                      |   | min     | typ  | max |      |
| Input Capacitance            | Ciss                 | V <sub>DS</sub> =-20V, f=1MHz           |         | 160  |     | pF   |
| Output Capacitance           | Coss                 | V <sub>DS</sub> =-20V, f=1MHz           |         | 60   |     | pF   |
| Reverse Transfer Capacitance | Crss                 | V <sub>DS</sub> =-20V, f=1MHz           |         | 10   |     | pF   |
| Turn-ON Delay Time           | t <sub>d(on)</sub>   | See specified Test Circuit              |         | 10   |     | ns   |
| Rise Time                    | t <sub>r</sub>       | See specified Test Circuit              |         | 13   |     | ns   |
| Turn-OFF Delay Time          | t <sub>d</sub> (off) | See specified Test Circuit              |         | 70   |     | ns   |
| Fall Time                    | t <sub>f</sub>       | See specified Test Circuit              |         | 30   |     | ns   |
| Diode Forward Voltage        | V <sub>SD</sub>      | I <sub>S</sub> =-1A, V <sub>GS</sub> =0 |         | -0.9 |     | V    |

### **Switching Time Test Circuit**







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